## 國立彰化師範大學 102 學年度 碩士班 招生考試試題

## 系所:<u>電信工程學研究所</u>

## 選考甲

科目:<u>電子學</u>

☆☆請在答案紙上作答☆☆

共1頁,第1頁

1. From Fig. 1 find  $v_x/v_1$  and  $v_0/v_1$ . (20 %)





- 2. A diode has a 0.7-V drop at a current of 2 mA and n = 2. What is the diode conducting current at  $V_D$  = 0.8 V, and what is the diode voltage drop at  $I_D$  = 10 mA? (20%)
- 3. A CE amplifier utilizes a BJT with  $\beta = 100$  and  $V_A = 50$  V, biased at  $I_C = 0.5$  mA; it has a collector resistance  $R_C = 10$  k $\Omega$ , a resistance  $R_E = 100$   $\Omega$  is connected in the emitter. Find  $R_{in}$ ,  $A_{vo}$  and  $R_o$ . (20%)
- 4. An NMOS differential pair is biased by a current source I = 0.2 mA having an output resistance  $R_{CS}$  = 200 k $\Omega$ . The amplifier has drain resistances  $R_D = 20$  k $\Omega$ , using transistors with  $k'_n = 200 \ \mu A/V$ , W/L = 10, and neglecting  $r_o$ . If the output is taken differentially and there is a 2% mismatch between the drain resistances, find  $|A_d|$ ,  $|A_{cm}|$ , and CMRR. (20%)
- 5. A common-source amplifier has  $R_{in} = 200 \text{ k}\Omega$ ,  $R_D = 10 \text{ k}\Omega$ . The transistor has  $g_m = 2 \text{ mA/V}$ ,  $r_o = 100 \text{ k}\Omega$ ,  $C_{gs} = 1.5 \text{ pF}$ , and  $C_{gd} = 0.5 \text{ pF}$ . The amplifier is fed from a voltage source  $v_s$  with an internal resistance of 200 k $\Omega$  and is connected to a 10 k $\Omega$  load.

Find: (a) the overall midband voltage gain  $A_M = v_o / v_s$ . (b) the upper 3-dB frequency  $f_H$ . (20%)